

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

EMH2408 — General-Purpose Switching Device Applications

Features

- The EMH2402 incorporates an N-channel MOSFET that feature low ON-resistance and ultrahigh-speed switching, thereby enabling high-density mounting.
- 1.8V drive.
- · Halogen free cpmpliance.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		20	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	ID		4	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	16	Α
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm²X0.8mm) 1unit	1.0	W
Total Dissipation	PT	When mounted on ceramic substrate (900mm²X0.8mm)	1.2	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	ç

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2A	2.0	3.4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =4A, V _{GS} =4.5V		34	45	mΩ
	RDS(on)2	ID=1A, VGS=2.5V		49	67	mΩ
	R _{DS} (on)3	I _D =0.5A, V _{GS} =1.8V		74	115	mΩ

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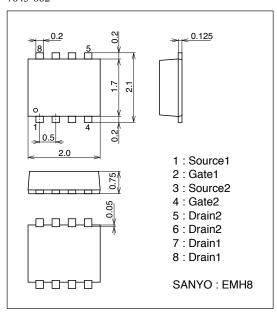
EMH2408

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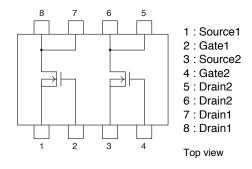
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		345		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		67		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		52		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		9.2		ns
Rise Time	t _r	See specified Test Circuit.		60		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		30		ns
Fall Time	tf	See specified Test Circuit.		38		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4.5V, I _D =4A		4.7		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4.5V, I _D =4A		0.65		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4.5V, I _D =4A		1.6		nC
Diode Forward Voltage	V _{SD}	I _S =4A, V _{GS} =0V		0.8	1.2	V

Package Dimensions

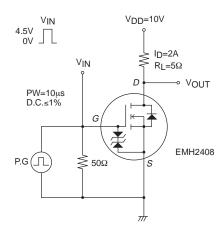
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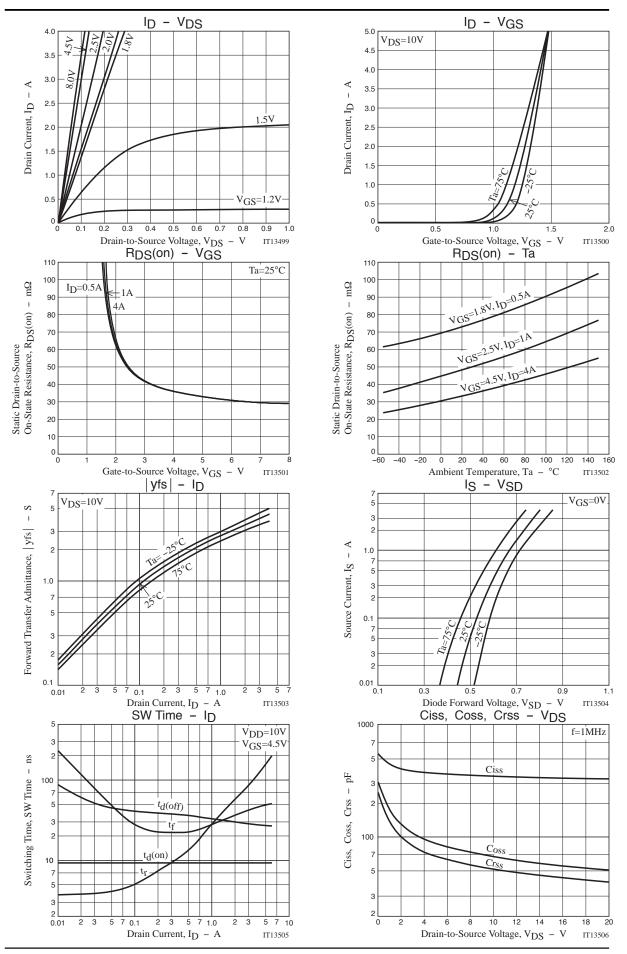


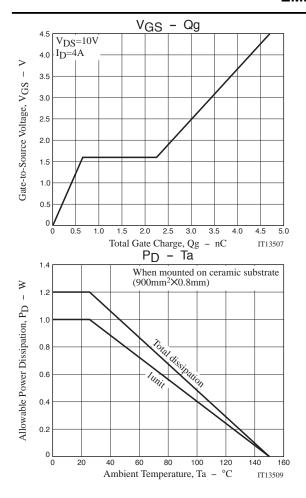
Electrical Connection

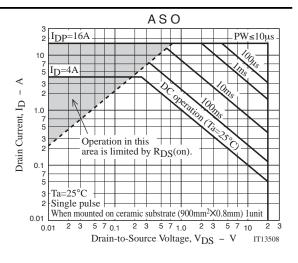


Switching Time Test Circuit









Note on usage: Since the EMH2408 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.ged objects.ged objects.

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